

KSE180/181/182

Low Power Audio Amplifier Low Current High Speed Switching Applications



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage : KSE180	60	V
	: KSE181	80	V
	: KSE182	100	V
V _{CEO}	Collector-Emitter Voltage : KSE180	40	V
	: KSE181	60	V
	: KSE182	80	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current (DC)	3	Α
I _{CP}	Collector Current (Pulse)	6	Α
I _B	Base Current	1	Α
P _C	Collector Dissipation (T _a =25°C)	1.5	W
	Collector Dissipation (T _C =25°C)	12.5	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CEO}	Collector -Emitter Breakdown Voltage : KSE180 : KSE181 : KSE182	I _C = 10mA, I _B = 0	40 60 80		V V
I _{CBO}	Collector Cut-off Current: KSE180: KSE181: KSE182: KSE180: KSE181: KSE181: KSE181: KSE182	$\begin{split} &V_{CB} = 60 \text{V, } I_B = 0 \\ &V_{CB} = 80 \text{V, } I_E = 0 \\ &V_{CB} = 100 \text{V, } I_E = 0 \\ &V_{CB} = 60 \text{V, } I_E = 0 \textcircled{0} T_C = 150 ^{\circ}\text{C} \\ &V_{CB} = 80 \text{V, } I_E = 0 \textcircled{0} T_C = 150 ^{\circ}\text{C} \\ &V_{CB} = 100 \text{V, } I_E = 0 \textcircled{0} T_C = 150 ^{\circ}\text{C} \end{split}$		0.1 0.1 0.1 0.1 0.1 0.1	μΑ μΑ μΑ mA mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 7V, I_{C} = 0$		0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = 1V$, $I_C = 100$ mA $V_{CE} = 1V$, $I_C = 500$ mA $V_{CE} = 1V$, $I_C = 1.5$ A	50 30 12	250	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 500$ mA, $I_B = 50$ mA $I_C = 1.5$ A, $I_B = 150$ mA $I_C = 3$ A, $I_B = 600$ mA		0.3 0.9 1.7	V V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 1.5A$, $I_B = 150mA$ $I_C = 3A$, $I_B = 600mA$		1.5 2.0	V V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = 1V, I _C = 500mA		1.2	V
f _T	Current Gain Bandwidth Product	V _{CE} = 10V, I _C = 100mA	50		MHz
C _{ob}	Output Capacitance	$V_{CB} = 10V, I_{E} = 0, f = 0.1MHz$		30	pF

Typical Characteristics

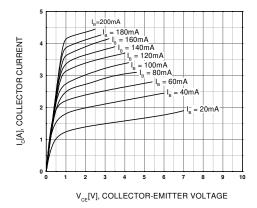


Figure 1. Static Characteristic

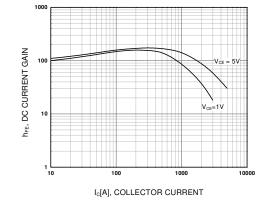


Figure 2. DC current Gain

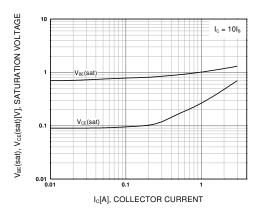


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

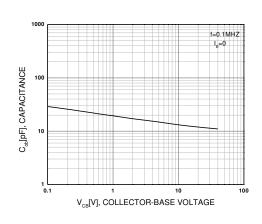


Figure 4. Collector Output Capacitance

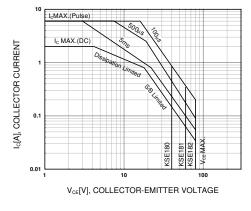


Figure 5. Safe Operating Area

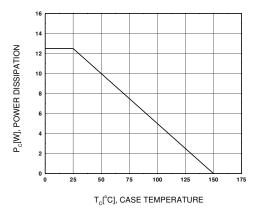
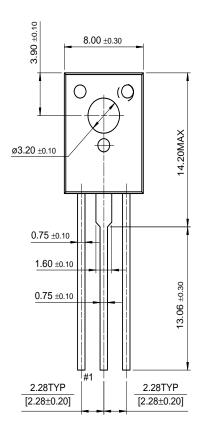
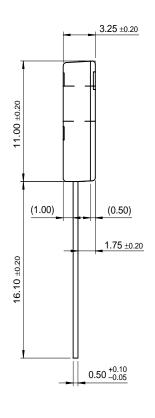


Figure 6. Power Derating

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Dimensions in Millimeters

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